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February 2008

74LVT2244, 74LVTH2244 Low Voltage Octal Buffer/Line Driver with 3-STATE Outputs and 25 Ω Series Resistors in the Outputs

Features

- Input and output interface capability to systems at 5V V_{CC}
- Equivalent 25Ω-Series resistors on outputs
- Bushold data inputs eliminate the need for external pull-up resistors to hold unused inputs (74LVTH2244), also available without bushold feature (74LVT2244)
- Live insertion/extraction permitted
- Power Up/Down high impedance provides glitch-free bus loading
- Outputs source/sink –12mA/+12mA
- Latch-up performance exceeds 500mA
- ESD performance:
 - Human-body model > 2000V
 - Machine model > 200V

Ordering I format.

- Charged-device model > 10(V

General Description

The LVT2244 and LVTH2244 ar loctal uffers and line drivers designed to be emrloy, as minory address drivers, clock drivers ar lous or inted ansmitters or receivers which provid in loved a board density. The equivalent 254. Perior resister is helps reduce output overshoot ar junder, pot.

The LVTr 244 ata in uts include bushold, eliminating the od to exto pull-up resistors to hold unused put

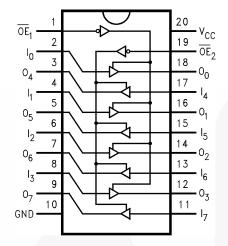
The coal buffers and line drives over designed for low-volte \Rightarrow (3.3V) V_{CC} applications, but with the capability to provide \Rightarrow The interface to a 5V environment. The 2VT2244 and LVTH2244 are fabricated with an adranced BiCMCS technology to achieve high speed operation similar to 5V ABT while maintaining low power dissipation.

	N. 1b.	Packag ÷ Numoor	Package Description
4	1.VT22 WI	M20B	20-Lead Smal Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
	74. T2 [~] 4SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
	74LV , 2244M.T.C	1/17C20	20-1 ead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
	74LVTF2244WM	M.20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
	74'_VTH2244SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
	74LVTH2244MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering number.

All packages are lead free per JEDEC: J-STD-020B standard.

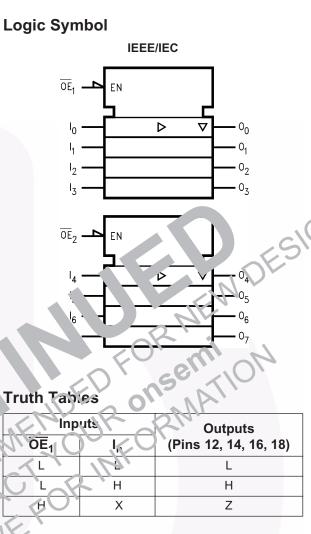
Connection Diagram



Pin Description

Pin Names	Description
$\overline{OE}_1, \overline{OE}_2$	3-STATE Output Enable Inputs
I ₀ —I ₇	Inputs
O ₀ –O ₇	Outputs

AIS DEVICE PLEASE



Inp	uts	Outputs
\overline{OE}_2	I _n	(Pins 3, 5, 7, 9)
L	L	L
L	Н	Н
Н	Х	Z

H = HIGH Voltage Level

L = LOW Voltage Level X = Immaterial

Z = High Impedance

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Rating
V _{CC}	Supply Voltage	-0.5V to +4.6V
VI	DC Input Voltage	-0.5V to +7.0V
Vo	DC Output Voltage	
	Output in 3-STATE	-0.5V to +7.0V
	Output in HIGH or LOW State ⁽¹⁾	-0.5V to +7.0V
I _{IK}	DC Input Diode Current, V _I < GND	_50mA
I _{OK}	DC Output Diode Current, V _O < GND	-50mA
Ι _Ο	DC Output Current, V _O > V _{CC}	
	Output at HIGH State	64mA
	Output at LOW State	128mA
I _{CC}	DC Supply Current per Supply Pin	±64mA
I _{GND}	DC Ground Current per Ground Pin	±128mA
T _{STG}	Storage Temperature	_65° C tc → 150°C

Note:

1. I_O Absolute Maximum Rating must be o' ved.

Recommended Operation Cor itions

The Recommended Operating Contributions able defines the conditions for actual device operation. Recommended operating conditions are pecified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend excessing the noric signing to account maximum ratings

Symb '	Parameter	Min.	Max.	Units
	S voltage	2.7	3.6	V
V _I	put Voltage	0	5.5	V
IOF,	HIGH-Level Orapul Current		-12	mA
OL	LOW-Level Output Curlent		12	mA
TĄ	Free-Air Operating Temperature	-40	85	°C
$\Delta^{t}/\Delta V$	Input Edge Rpte, V _{IN} = 0.8V–2.0V, V _{CC} = 3.0V	0	10	ns/V
$\Delta^{t}/\Delta V$	Input Edge Rate, $V_{IN} = 0.8V-2.0V$, $V_{CC} = 3.0V$	0	10	

					$T_A = -4$	40°C to +	85°C	
Symbol	Parame	eter	V _{CC} (V)	Conditions	Min.	Typ. ⁽²⁾	Max.	Units
V _{IK}	Input Clamp Diode \	/oltage	2.7	I _I =18mA			-1.2	V
V _{IH}	Input HIGH Voltage		2.7–3.6	$V_0 \le 0.1V$ or	2.0			V
V _{IL}	Input LOW Voltage		2.7–3.6	$V_{O} \ge V_{CC} - 0.1V$			0.8	V
V _{OH}	Output HIGH Voltage	е	2.7–3.6	I _{OH} = -100μA	V _{CC} - 0.2			V
			3.0	$I_{OH} = -12 mA$	2.0			
V _{OL}	Output LOW Voltage)	2.7	$I_{OL} = 100 \mu A$			0.2	V
			3.0	$I_{OL} = 12mA$			0.8	
I _{I(HOLD)} ⁽³⁾	Bushold Input Minim	ium Drive	3.0	$V_I = 0.8V$	75			μA
				$V_{I} = 2.0V$	-75			25
I _{I(OD)} ⁽³⁾	Bushold Input Over-Drive Current to		3.0	(4)	5			ĻΆ
	Change State			(5)	·50L		N,	
ц	Input Current		3.6	V _I = 5.5V			10	μA
		Control Pins	3.6	$V_{I} = 0V \text{ or } V_{CC}$		0 10.	±1	
		Data Pins	3.6				-5	
					K	10	1	
I _{OFF}	Power Off Leakage	Current	L	$V \leq V_{\rm I}$ $V_{\rm O} \leq 5.5$		5	±100	μA
I _{PU/PD}	Power up/down 3-ST Output Current	TATE	ι`.5	V = 0.5V to ≤.0V' V _I = GND >: V' _{CC}	20	JNP	±100	μA
I _{OZL}	3-STATE Output Lea	ikagr un +	3.0	$V_{\rm O} = 0.5V$			-5	μA
I _{OZH}	3-STATE Output Lea	aka Curren	3.6	V _C = 3.0V			5	μA
I _{OZH} +	3-STATE Outr	kag, `urrer	3.6	$V_{CC} < V_O \le 5.5V$			10	μA
I _{CCH}	Power Suppl Curre	nt	3.3	Outouts HIG'1			0.19	mA
I _{CCL}	Pov Gupply Te	n'	3.6	Outputs LOW			5	mA
I _{CCZ}	Pow_app. Curre	nt	3.5	Ou p. ts Disabled			0.19	mA
	i ver j Curre	CK	3.6	$V_{CC} \le V_O \le 5.5V$, Outputs Disabled			0.19	mA
'sc	ncrease in Power S	upply Current ⁽⁶⁾	3.6	One Input at $V_{CC} - 0.6V$, Other Inputs at V_{CC} or GND			0.2	mA

Notes:

2. All typical values are at $V_{CC} = 3.3V$, $T_A = 25^{\circ}C$.

DC Electrical Characteristics

3 Applies to bushold versions only (74LVTH2244).

4. An external driver must source at least the specified current to switch from LOW-to-HIGH.

5. An external driver must sink at least the specified current to switch from HIGH-to-LOW.

6. This is the increase in supply current for each, input that is at the specified voltage level rather than V_{CC} or GND.

Dynamic Switching Characteristics⁽⁷⁾

			Conditions	Т	A = 25°	С	
Symbol	Parameter	V _{CC} (V)	$C_L = 50 pF, R_L = 500 \Omega$	Min.	Тур.	Max.	Units
V _{OLP}	Quiet Output Maximum Dynamic V _{OL}	3.3	(8)		0.8		V
V _{OLV}	Quiet Output Minimum Dynamic V _{OL}	3.3	(8)		-0.8		V

Notes:

7. Characterized in SOIC package. Guaranteed parameter, but not tested.

8. Max number of outputs defined as (n). n-1 data inputs are driven 0V to 3V. Output under test held LOW.

AC Electrical Characteristics

		Vee		-4 [^] C 1 50pi R _L 1.3V	ວ°C, 50 	2.71	
Symbol	Parameter	Min.	- τνμ (9)		Min.	Max.	Units
t _{PLH}	Propagation Delay Data to Output			4.4	1.0	5.3	ns
t _{PHL}		1.6		4.1	1.2	4.4	
t _{PZH}	Output Enable Time	1.0		5.9	1.0	7.7	ns
t _{PZL}		1	<u>N</u>	÷).5	1.1	6.2	
t _{PHZ}	Output Disable Time	1.9		6.1	1.9	6.8	ns
t _{PLZ}		1.8	10	.4.5	1.8	4.5	
t_{OSHL}, t_{OSLH}	Output to are at S. v ⁽¹⁰⁾		5	1.0		1.0	ns

Notes:

9. All typical you as are \sim V $_{\rm A}$ = 25°C.

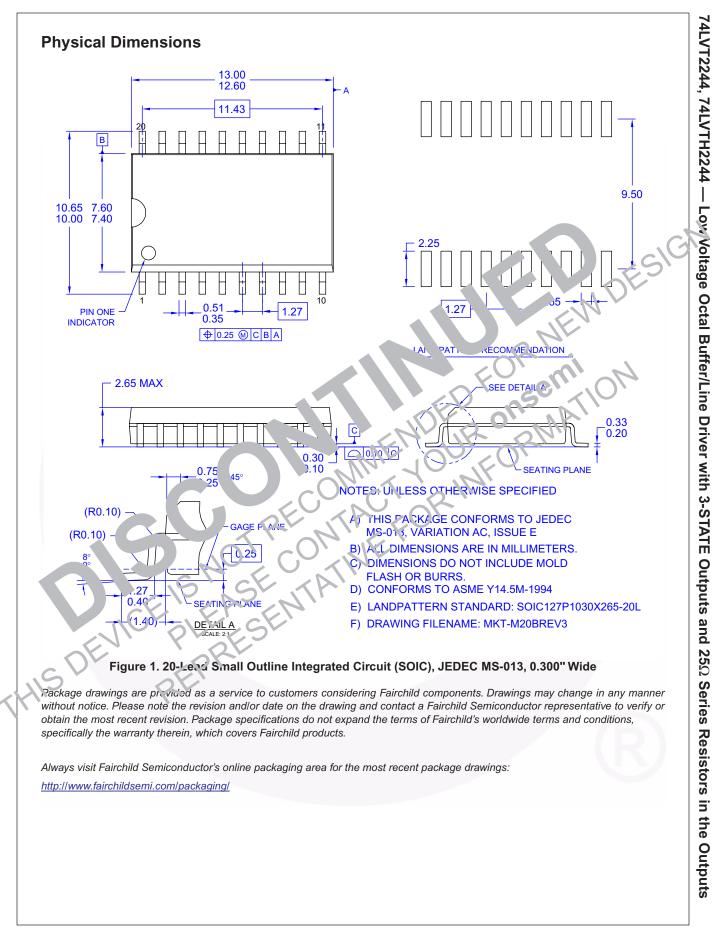
10. Skew de. as e absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, onthe 'Hile -to-Low (t_{OSHL}) or LOW-to-HIGH (t_{OSHL}).

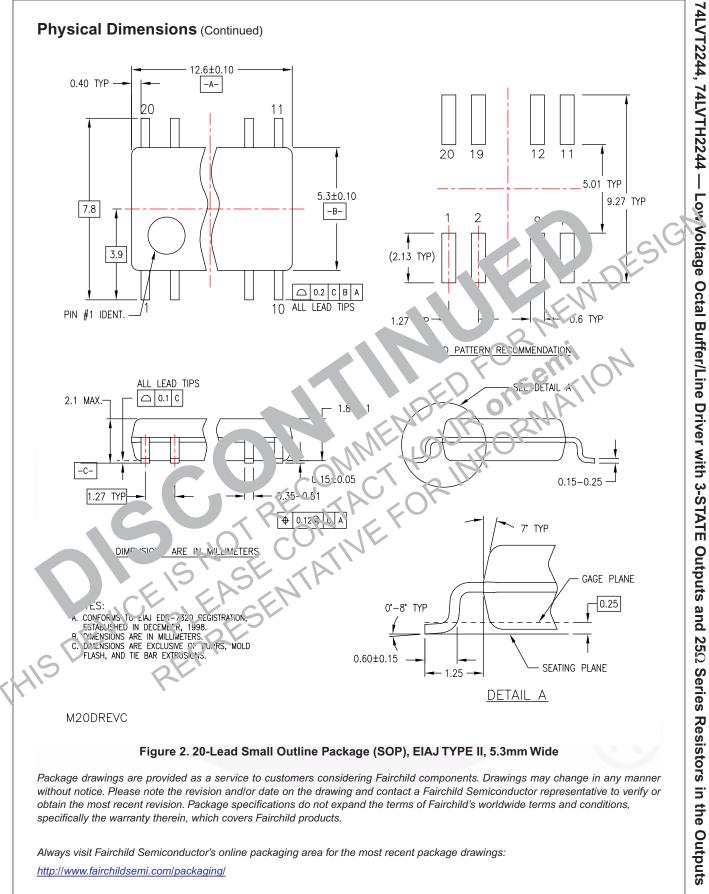
Cap Jitance⁽¹¹⁾

Symbol	Pararieter	Conditions	Typical	Units
C _{IN}	Input Capacitance	$V_{CC} = 0V, V_I = 0V \text{ or } V_{CC}$	3	pF
C _{OUT}	Output Capacitance	V_{CC} = 3.0V, V_{O} = 0V or V_{CC}	6	pF

Note:

11. Capacitance is measured at frequency f = 1MHz, per MIL-STD-883B, Method 3012.





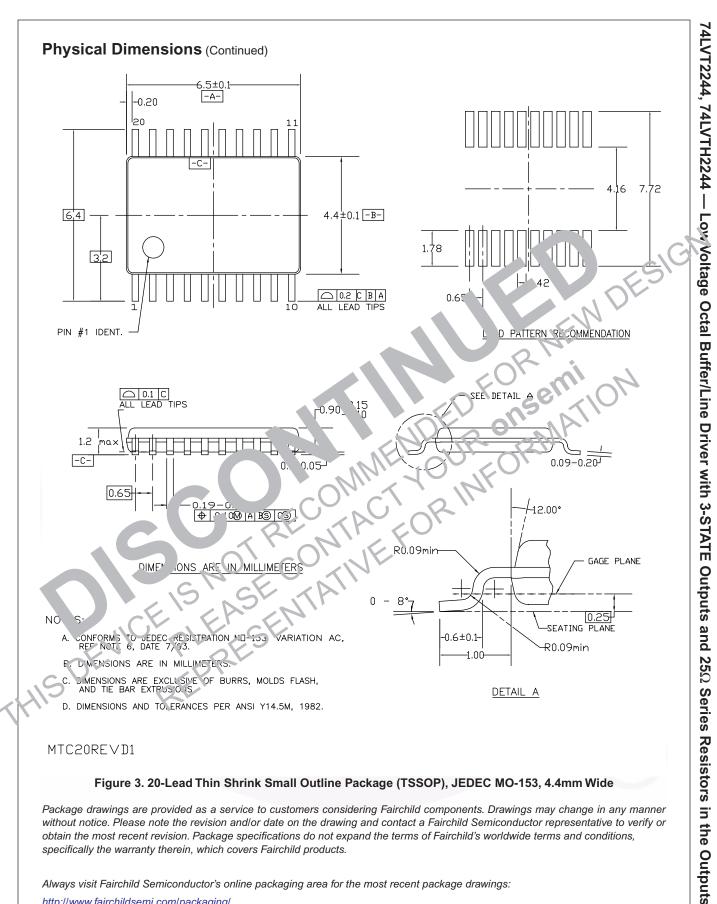


Figure 3. 20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

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